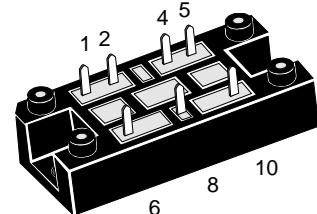
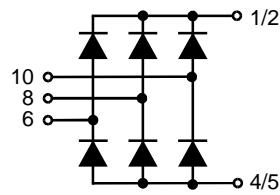


# Three Phase Rectifier Bridge

**V<sub>RRM</sub> = 1200 V**  
**I<sub>dAV</sub> = 50 A**  
**t<sub>rr</sub> = 40 ns**

V <sub>RSM</sub> V	V <sub>RRM</sub> V	Type
1200	1200	VUE 50-12NO1



Symbol	Test Conditions	Maximum Ratings		
I <sub>dAV</sub>	T <sub>K</sub> = 85°C, module	50	A	
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; V <sub>R</sub> = 0	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	200 210	A A
	T <sub>VJ</sub> = T <sub>VJM</sub> V <sub>R</sub> = 0	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	185 195	A A
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C V <sub>R</sub> = 0	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	200 180	A <sup>2</sup> s A <sup>2</sup> s
	T <sub>VJ</sub> = T <sub>VJM</sub> V <sub>R</sub> = 0	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	170 160	A <sup>2</sup> s A <sup>2</sup> s
T <sub>VJ</sub>			-40...+150	°C
T <sub>VJM</sub>			150	°C
T <sub>stg</sub>			-40...+125	°C
V <sub>ISOL</sub>	50/60 Hz, RMS I <sub>ISOL</sub> ≤ 1 mA	t = 1 min t = 1 s	3000 3600	V~ V~
M <sub>d</sub>	Mounting torque (M5) (10-32UNF)		2 - 2.5 18-22	Nm lb.in.
Weight	typ.		35	g

Symbol	Test Conditions	Characteristic Values		
		typ.	max	
I <sub>R</sub>	V <sub>R</sub> = V <sub>RRM</sub> V <sub>R</sub> = 0.8 V <sub>RRM</sub>	T <sub>VJ</sub> = 25°C T <sub>VJ</sub> = 125°C	4	0.75 mA 7 mA
V <sub>F</sub>	I <sub>F</sub> = 30 A;	T <sub>VJ</sub> = 25°C		2.55 V
V <sub>T0</sub>	For power-loss calculations only		1.65 V 18.2 mΩ	
r <sub>T</sub>				
R <sub>thJS</sub>	per diode, per module,	120° rect. 120° rect.	1.5 K/W 0.25 K/W	
I <sub>RM</sub>	I <sub>F</sub> = 30 A, -di <sub>F</sub> /dt = 240 A/μs V <sub>R</sub> = 540 V, L ≤ 0.05 μH, T <sub>VJ</sub> = 100°C	16	18 A	
t <sub>rr</sub>	I <sub>F</sub> = 1 A; -di/dt = 100 A/μs; V <sub>R</sub> = 30 V, T <sub>VJ</sub> = 25°C	40	60 ns	
d <sub>s</sub>	Creeping distance on surface		12.7 mm	
d <sub>A</sub>	Creepage distance in air		9.4 mm	
a	Max. allowable acceleration		50 m/s <sup>2</sup>	

Data according to IEC 60747 and refer to a single diode unless otherwise stated.  
IXYS reserves the right to change limits, test conditions and dimensions.

## Features

- Package with DCB ceramic base plate
- Isolation voltage 3600 V~
- Planar passivated chips
- Leads suitable for PC board soldering
- Creeping and creepage-distance fulfils UL 508/CSA 22.2NO14 and VDE 0160 requirements
- Epoxy meet UL94V-O
- UL registered E72873

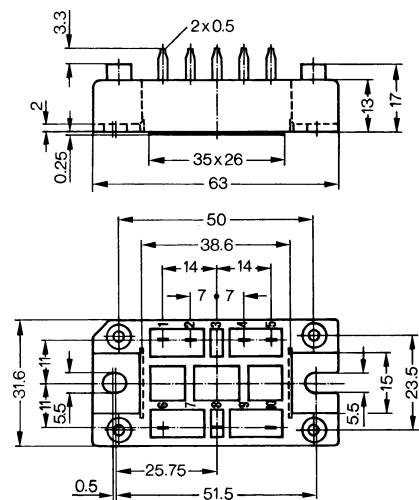
## Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Output filter for PWM inverter

## Advantages

- Reduced EMI/RFI
- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling

## Dimensions in mm (1 mm = 0.0394")



Use output terminals in parallel connections

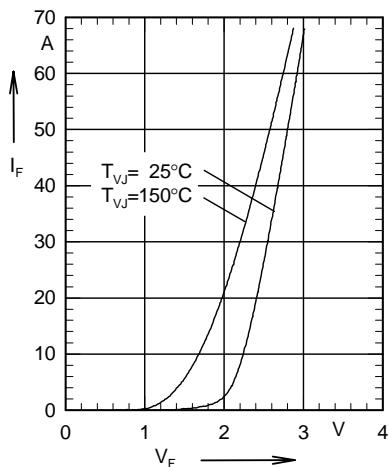


Fig. 1 Forward current versus voltage drop per diode.

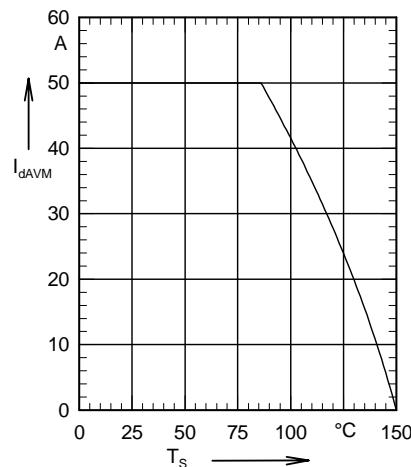


Fig. 2 Maximum forward current at heatsink temperature  $T_S$ .

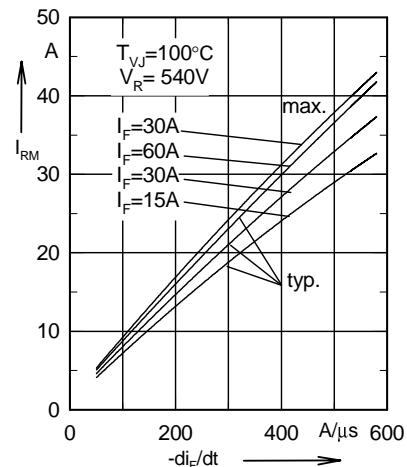


Fig. 3 Typical peak reverse current versus  $-di_F/dt$ .

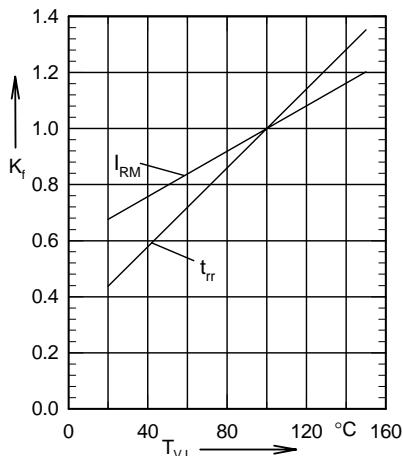


Fig. 4 Dynamic parameters versus junction temperature.

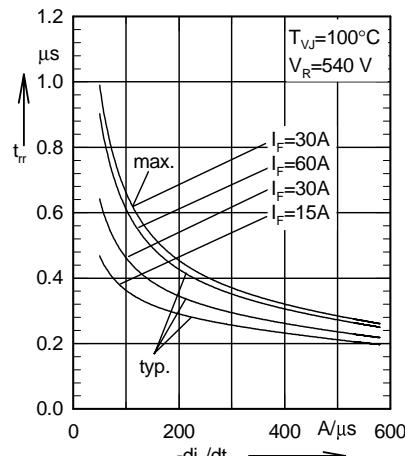


Fig. 5 Typical recovery time versus  $-di_F/dt$ .

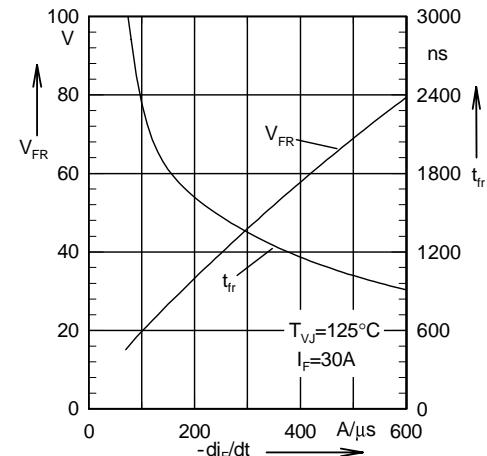


Fig. 6 Typical peak forward voltage and forward recovery time versus  $-di_F/dt$ .

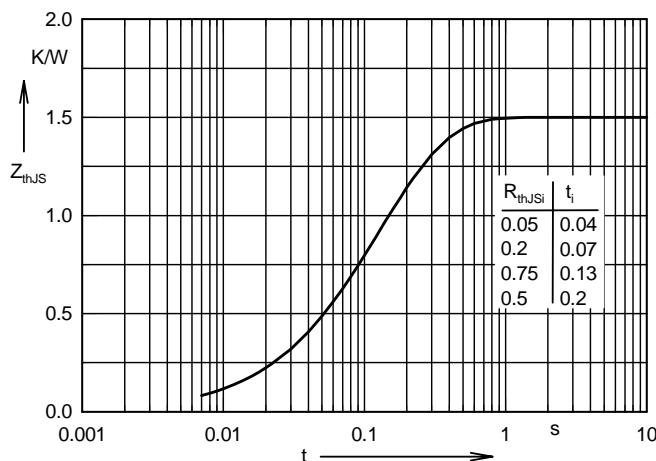


Fig. 7 Transient thermal impedance junction to heatsink

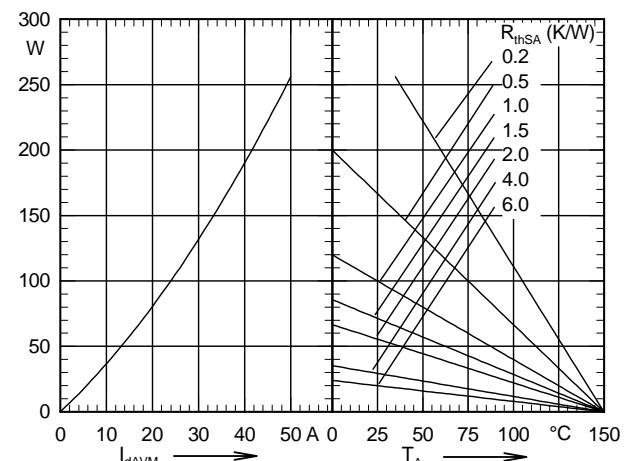


Fig. 8 Power dissipation versus direct output current and ambient temperature